

Effective from Session	Effective from Session: 2024-25								
Course Code	DMA-101	Title of the Course	APPLIED MATHEMATICS-I	L	Т	Р	С		
Year	I <sup>st</sup>	Semester	1 <sup>st</sup>	03	01	00	-		
Pre-Requisite	DMA-101	Co-requisite	NA						
Course Objectives	To know the basic concep	now the basic concepts of Mathematics with their Applications in Engineering.							

	Course Outcomes
CO1	Arithmetic Progression and Geometric Progression can be applied in real life by analyzing a certain pattern that we see in our daily life.
CO2	Trigonometry is widely used in several fields. Some of its uses are Measuring heights and distances, in construction and architecture, flight engineering, marine
	biology, application of Physics, electrical engineering, manufacturing industry, gaming industry.
CO3	The concept of Complex Number is used in the field of Computer Science. It is also used in coding and programming.
CO4	Here students are getting the knowledge of Graphs, continuity, and differentiation by which they will be able to find areas of any surface.
CO5	By getting full knowledge of Tangent and normal students will be able to use it in daily lives and further studies in Architecture Engineering, Civil Engineering
	etc.

Unit No.	Title of the Unit		Contact Hrs.	Mapped CO
1.	i) Series ii) Binomial Theorem iii) Determinants	<ul> <li>Series:</li> <li>Arithmetical Progression: nth term of AP, Sum of 'n' terms, Arithmetic Mean.</li> <li>Geometrical Progression: nth term of GP, Sum of 'n' terms&amp; infinite terms, Geometric Mean.</li> <li>Binomial theorem: Definition of factorial notation, permutation and combination, Binomial theorem for positive index, negative and fractional index (without proof), Application of Binomial theorem.</li> <li>Determinants: Definition, expansion and elementary properties of determinant of order 2 and 3. Solution of system of linear equations, Consistency of equations, Cramer's rules.</li> </ul>	08	1
	i) Trigonometry	Trigonometry: Relation between sides and angles of triangles: Simple cases only.		
	ii) Vector Algebra	Vector Algebra: Dot and Cross product, Scalar and vector triple product.	07	2
3.	Complex Number	<b>Complex Number:</b> Definition of imaginary number, complex number & its conjugate. Algebra of complex number (equality, addition, subtraction, multiplication and division). Geometrical representation of a complex number, modulus and amplitude. Polar form of a complex number, Square root of a complex number. De Moivre's theorem (without proof) & its application.	08	3
4.	Differential Calculus-I	<ul> <li>Differential Calculus-I</li> <li>Functions, limits, continuity: Definitions of variable, constant, intervals (open, closed, semi-open). Definition of function, elementary methods of finding limits (right and left), elementary test for continuity and differentiability.</li> <li>Methods of finding derivative: Fundamental rules of derivatives (Sum and Difference), Derivatives of special functions, Trigonometric functions, exponential function, Function of a function.</li> </ul>	09	4
5.	Differential Calculus-II	Differential Calculus - II Differentiation: Logarithmic differentiation, Function with respect to another function, Function power function, Higher order derivatives. Application: Finding Tangents, Normal. Maxima/Minima.	08	5
Referenc	es Books:			
1. Applied	Mathematics: Dr. Kailash Sinh	a, Meerut publication.		
2. Applied	Mathematics: P. K. Gupta, Asi	an Publication.		
3. Applied	Mathematics: H. R. Loothara,	Bharat Bharti Publication		

4. Mathematics for Polytechnic: S.P. Deshpande, Pune Vidyarthi Griha.

e-Learning Source:

https://youtu.be/syLIPtxjN0E?si=OrM4IRejVzgmwWpl

PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PSO1	PSO2	PSO3	PSO4
CO1	3	1	3	-	1	-	-	2	-	1	1
CO2	1	3	1	1	2	-	-	2	1	2	-
CO3	-	1	2	2	3	-	-	3	2	2	1
CO4	2	2	2	1	-	-	-	-	2	1	3
CO5	2	1	2	3	1	-	-	-	1	-	2

Name & Sign of Program Coordinator	Sign & Seal of HoD



Effective from Sessi	on: 2010						
Course Code	DPH-101	Title of the Course	Applied Physics-I	L	Т	Р	С
Year	Ι	Semester	Ι	3	1	0	
Pre-Requisite	None	Co-requisite	None				
Course Objectives		nem to analyze physical	pts of units, dimensions, dimensional analysis, measuremen equations, perform unit conversions, estimate errors, and ap				

	Course Outcomes
CO1	Students learn to convert one unit to different unit and they use conversation factor which is numerically quantity that we multiply
	or divide to the quantity. Student learns accuracy of the lab instrument with the help of significant figure.
CO2	In this student learn investigate the effect of gravity and friction on the motion of machines (mechanical) instrument etc.
CO3	Fundamental concepts of electrochemistry, including oxidation-reduction (redox) reactions, electrolytes, electrodes, and
	electrochemical cells.
CO4	Explain the fundamental principles of chemical kinetics, including the definition of reaction rate, rate laws, and the role of molecular
	collisions in reactions.
CO5	Identify and explain various physical, chemical, and biological parameters of water quality, including turbidity, pH, dissolved
	oxygen, hardness, and biological oxygen demand (BOD). Understand modern water purification technologies like reverse osmosis
	(RO), ultrafiltration (UF), ion exchange, and membrane filtration, and their applications in industrial and municipal water treatment.

Unit No.	Title of the Unit		Contact Hrs.	Mapped CO
Unit-1	Measurement & Vector	<b>Measurement:</b> Units and Dimensions, Fundamental and derived units: S.I. Units and Dimensions of physical quantities, Dimensional formula and dimensional equation, Principal of homogeneity and application of homogeneity principle to:(i) Checking the correctness of physical equations (ii)Deriving relations among various physical quantities, (iii)Conversion of numerical values of physical quantities form one system of units into another, Limitations of dimensional analysis, Errors in measurement, accuracy and precision, random and systematic errors, estimation of probable errors in the result of measurement (combination of errors in addition, subtraction, multiplication and power). Significant figures and order of accuracy in respect to instruments. <b>Vector</b> : Scaler and vector quantities; Addition, Subtraction, Resolution of vector; Cartesian components of vector, Scaler and vector product of vectors	6	CO-1
Unit-2	Force and Motions, Fluid mechanics and fiction, Work, Power and Energy	<ul> <li>Force and Motions: Newton's Law of Motion, Circular motion, angular velocity, angular acceleration and centripetal acceleration. Relationship between linear velocity and angular velocity, Relationship between linear acceleration and angular acceleration.</li> <li>Fluid mechanics and fiction: Surface tension, capillaries, equation of continuity, Bernoulli's theorem, stream line and turbulent flow, Reynold's number. Physical significance of friction, Advantage and disadvantage of friction and its role in everyday life, Static and dynamic frictional forces, Coefficients of static and dynamic frictions and their measurement, Viscosity, Coefficients of viscosity and its determination by Stoke's method.</li> <li>Work, Power and Energy: Work done by force on bodies moving on horizontal and inclined planes in presence of frictional forces, Concept of power and its units, Calculation of power (simple cases). Concept of kinetic and potential energy, various forms of energy, conservation of energy, Force constant of spring, Potential energy of stretched spring.</li> </ul>	10	CO-2
Unit-3	Elasticity	<b>Elasticity:</b> Stress and Strain, Hooke's law, Elastic limit, Yielding point and breaking point, Modulus of elasticity, Young's modulus, Bulk modulus and modulus of rigidity, Poisson ratio, Resilience. Simple Harmonic Motion, Periodic Motion, Characteristics of Simple Harmonic Motion, Equation of Simple Harmonic Motion and determination of Velocity and acceleration, Graphical representation, Spring Mass system, Simple pendulum, Derivation of their periodic time, Energy conservation in Simple Harmonic Motion, Definition of free, Forced, undamped and damped vibrations, Resonance and its sharpness, Q-factor.	8	CO-3
Unit-4	Gas laws and specific heats of gases	Boyle's law, Charle's law, Gay Lussac's law, Absolute temperature, Kelvin scale of temperature, General gas equation(without derivation), Molar or universal gas constant, Universal gas equation, Standard or normal temperature and pressure (N.T.P), Specific heat of gases, Relation between two specific heat, Thermodynamics variables, first law of thermodynamics(statement and equation only), Isothermal, Isobaric, Isochoric and adiabatic processes (Difference among these processes and equation of state).		CO-4
Unit-5	Heat transfer and radiation	Heat transfer and radiation: Modes of heat transfer, Coefficient of thermal conductivity and its determination by (i) Searle's Method for good conductors. (ii) Lee's Method for poor conductors. Conduction of heat through compound media, Conduction and convection, Radial flow of heat, Blackbody radiation, Stefan's law, Wein's displacement and Rayleigh-Jeans laws, Planck's law.	Q	CO-5
Referen	ices Books:			
	Nootan Physics:			
	Applied Physics:			
		ental: Gogia & Gomber.		
	Applied Physics: ng Source:	r.o. Kusiiwana.		
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PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3	PSO4	PSO5
C01	3								2		3	3	1		2	3	2
CO1 CO2	3								2		2	$\frac{3}{2}$	1			5	2
CO3	3	1									2	1					2
CO4	2	2										1					2
CO5	2			2								1					2

## 1-Low Correlation; 2- Moderate Correlation; 3- Substantial Correlation

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Name & Sign of Program Coordinator	Sign & Seal of HoD

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Effective from Sessi	Effective from Session:								
Course Code	DCH-101	Title of the Course	Applied Chemistry-I	L	Т	Р	С		
Year	Ι	Semester	Ι	3	1	0	-		
Pre-Requisite	-	Co-requisite	-						
Course Objectives	2. To provide exam	. To understand all the chemical reactions, principle and theory related to topics							

	Course Outcomes
CO1	By applying knowledge of atomic structure and periodic properties to real-world engineering challenges, such as enhancing the performance of electronic devices, improving energy efficiency, or designing corrosion-resistant materials.
CO2	To explain the fundamental types of chemical bonds (ionic, covalent, and metallic) and their significance in determining the properties of engineering materials.
CO3	Fundamental concepts of electrochemistry, including oxidation-reduction (redox) reactions, electrolytes, electrodes, and electrochemical cells.
CO4	Explain the fundamental principles of chemical kinetics, including the definition of reaction rate, rate laws, and the role of molecular collisions
004	in reactions.
	Identify and explain various physical, chemical, and biological parameters of water quality, including turbidity, pH, dissolved oxygen, hardness,
CO5	and biological oxygen demand (BOD). Understand modern water purification technologies like reverse osmosis (RO), ultrafiltration (UF), ion
	exchange, and membrane filtration, and their applications in industrial and municipal water treatment.

Unit No.	Title of the Unit		Contact Hrs.	Mapped CO
1	Atomic Structure Classification of Elements	Basic concept of atomic structure, Matter wave concept, Quantum number, Heisenberg's uncertainty principle, Shapes of orbital Modern classification of elements (s, p, d, and f block elements), periodic	8	1
2	Chemical Bonding	properties: ionization potential, electro negativity, electron affinity. Overview of basic concept of Ionic, Covalent & Co-ordinate bonds, Hydrogen bonding, Valence bond theory, Hybridization, VSEPR theory, Molecular orbital theory.	8	2
3	Electrochemistry -I & II	Arrhenius theory of electrolytic dissociation, Transport number, Electrolytic conductance, Ostwald dilution law. Concept of acid and bases: Arrhenius, Bronsted & Lewis theory. Concept of pH and numerical. Buffer solutions, Indicators, Solubility product, Common ion effect with their application. Redox reactions, electrode potential (Nernst equation), Electro-chemical cell (Galvanic & Electrolytic). EMF of a cell & free energy change. Standard electrode potential, Electrochemical series & Application. Chemical & electrochemical theory of corrosion, Galvanic Series. Prevention of corrosion by various methods.	8	3
4	Chemical Kinetics Catalysis Solid State	<ul> <li>Introduction, Law of mass action, order and molecularity of reaction. Activation energy, rate constants, 1st order reactions and 2nd order reactions.</li> <li>Definition, catalytic reactions properties, Catalytic promoters &amp; poison, autocatalysis &amp; negative catalysis. Theory of catalysis &amp; applications.</li> <li>Types of solids (Amorphous and Crystalline), classification (Molecular, Ionic, Covalent and Metallic), Band theory of solids (Conductors, Semiconductors &amp;</li> </ul>	8	4
5	Water Treatment	Insulators), types of crystals, FCC, BCC, Crystal imperfection. Hardness of water, its limits and determination of hardness of water by EDTA method. Softening methods (Soda lime, Zeolite and Ion exchange resin process). Disadvantages of hard water in different industries, scale & sludge formation, corrosion, caustic embrittlement, priming & foaming in boilers. Disinfection of Water by chloramine-T, Ozone and chlorine. Advantages and disadvantages of chlorination. Industrial waste & sewage, Municipality waste water treatment, Definition of BOD & COD. Numerical problems based on topics.	8	5
	nces Books:			
	d Chemistry: R. S. Katiyar ar			
	d Chemistry: Rakesh Kapoor			
	bles of General and Inorganic eering Chemistry: S. Chandra			
e	ed Chemistry: M. Gupta			
- Applie	. a			

e-Learning Source:

https://docs.google.com/document/d/1f9FaU1Y8D6D\_5DRCJXXIunGXageT23G0/edit?usp=drive\_link&ouid=106019737385905957374



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DO DOO												J
PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO12	PSO1	PSO2	PSO3	PSO4
C01	03		01				01					
CO2	03		-									
CO3	03		01				02					
CO4	03	01	02				02					
CO5	03		-				02					

1-Low Correlation; 2- Moderate Correlation; 3- Substantial Correlation

Dr. Rida Sagheer Name & Sign of Program Coordinator



	Effective	e from Sessi	on: 2013-14							
Pre-Regulative         Concent of the concentration of the direct and sequence of the concentration of concenting conconcentration of concentration of conconfiguration. Conce	Course	Code	DEC-102		Title of the Course	Electronics Components & Devices-I	L	P	С	
Conserved by the subscription of the disk and is related application.         Conserved of the understanding of the disk and is related application.           Conserved by the understanding of the disk and is related application.         Section 1000000000000000000000000000000000000	Year		Ι		Semester	Ι	3	0	-	
Same Objectives       2. To provide the understanding of the diode and its related application         Support of the understanding of the transistor and its related application.         Cursue Subscience         Cursue Subscience         Comparison of CL and KVI.         Constant of the understanding of the transistor parameter the constance the.         Constant of the understanding of the diode and its magnification as an amplifier.         Conduction of CL and KVI.         Conduction of the Unit         Intrinsic Semiconductors Conductivity, atomic and crystal structure of germanium and silicon, correlation and scombination. effect of temperature on conductivity of intrinsic semiconductors. Concey levels diagram of conductor, a instalators and intrinsic semiconductors. Concey levels diagram of conductivity. Definition of Drift and Diffusion currents.       8       1         Provide the unit         Intrinsic semiconductor RAN type semiconductors and their conductivity, Definition of Drift and Diffusion currents.       8       2         Objective Drive Statistics and conductor RAN type semiconductors and their conductivity. Definition of Drift and Diffusion currents.       8       2         Objective Statistics and their operation calculations of ripple factor and avalanche breakdown. Semiconductor RAN type semiconductors and their conductivity. Definition of Drift and Diffusion current flow in PN junction. Accel Tantecheir Statist	Pre-Req	luisite			—					
COI         Evaluate the basic circuits parameters like values, current, resistance circuit         Contracting constraints of KCL and KVI.           CO3         Characterize Semiconductor Hode and is application.         Contract Contracting Semiconductor Hode and is application.         Contracting Semiconductor Hode and is application.         Contracting Semiconductors.         Contract Mappe           CO4         Characterize and configure the BT.         Contract Mappe         Contract Mappe <td>Course</td> <td>-</td> <td>2. To provi</td> <td>de the und</td> <th>derstanding of the dio derstanding of the tran</th> <td>de and its related application nsistor and its related application.</td> <td></td> <td></td> <td></td>	Course	-	2. To provi	de the und	derstanding of the dio derstanding of the tran	de and its related application nsistor and its related application.				
CO2         Analyze simple analog circuits but explication of KCL and KVL           CO4         Contract of ode and its application.           CO4         Contract of ode and its application.           CO4         Contract of ode and its application as an amplifier.           CO5         Detailed analysis of BIT and its application as an amplifier.           Contract for the Unait         Intrinsic Semiconductors.         Contract for temperature on and silicon, covalent bonds, generation and recombination, effect of temperature on and silicon, covalent bonds, generation and recombination. Effect of temperature on conductivity of timins is semiconductors.         8         1           Semiconductor         Provide the Unait timis is semiconductors.         Contract for temperature on conductivity of timins is emiconductors.         8         1           Provides         Contract for the provide time of the provide tim	<u>CO1</u>	<b>F</b> 1 4 4	1							
CO3         Characterize Semiconductor diode and its application.           CO4         Contract Mappication.           CO5         Detailed analysis of HJT and its application as an amplifier.           CO5         Contract         Mappication.           Title of the Unit         Contract         Contract         Optimize Contract         Optimize Contract         Privation of Difficition of Contract         Mappication           Semiconductor         PS         PS         Semiconductor         PS         PS         PS         PS         Contract         PS         PS         PS         PS <th c<="" td=""><td></td><td></td><td></td><td></td><th></th><td></td><td></td><td></td><td></td></th>	<td></td> <td></td> <td></td> <td></td> <th></th> <td></td> <td></td> <td></td> <td></td>									
CO4         Characterize and configure the BT.         Context         Mappe           20         Detailed analysis of BT and its application as an amplifier.         Context         Mappe           1         Semiconductor         Intrinsic Semiconductors- Conductivity, atomic and crystal structure of germanium and silicon, covalent bonds, generation and recombination, effect of temperature on conductivity of intrinsic semiconductors.         8         1           2         Semiconductor         Physics         1         Strinsic Semiconductor Semiconductors and their conductivity. Definition of Drift and Diffusion currents.         8         2           2         Devices         Devices         Concept of rectification, specification of current flow in PN junction diode, mechanism of current flow in PN junction diode, mechanism of current flow in PN junction diode, with expectides (2ner diode, LED, photo diode, varactor diode, Schottky diode, tunnel diode).         8         2           3         Rectifiers & Wave Shaping and rectification of rectifiers, basic concept of florating and the argument of their concept of clopping and the argument of CBO.         8         3           4         Bipolar         Charge current, ICBO officet of temperature on leakage current, ICBO officet of temperature on and theakage current (ICBO) officet of temperature on and heakage curren										
COS         Detailed analysis of RT and its application as an amplifier.         Contact Mappe Mo.         Contact Title of the Unit         Contact Mappe CO           1         Semiconductor Physics         Intrinsic Semiconductors, conductivity, atomic and crystal structure of germanium and silicon, covalent bonds, generation and recombination, effect of temperature on conductivity of intrinsic semiconductors, energy levels diagram of conductor, Extrinsic semiconductors         8         1           2         Semiconductor Devices         PN junction diode, mechanism of current Row in PN junction, Zener and avalanche breakdown, Semiconductor of ode characteristics, static and dynamic resistances, Introduction to special purpose diodes (Zener diode, LED, photo diode, varactor diode, Schottky diode, tunnel diode).         8         2           3         Wave Shaping Circuit         Concept of rectification, specification of rectifier biasic concept of filtrating and filtering drivelits. Working and use of voltage-doubler circuit. Basic concept of lipping and rectification factor. (BCO) diamental current relations. Concept of Lakage current (ICBO) effect of temperature on leakage current in Charging circuits.         Charge carriers, PNP and NPN transistors, their symbols and mechanisms of current Now, Poplandion of fundamental current relations in CC econfiguration, collector current in terms of base current and lakage current in CC configuration (CB). Thous and output characteristics, determination of transistor parameters (input and output characteristics, determination of transistor as an amplifier in CC configuration. CD comparison of CB and CE configuration in any diffication. Transistor as an amplifier in CC configuration in amplification. Transistor biasing circuits for fi										
Unit No.         Title of the Unit         Context Item         Context CO         Mappe Context CO           1         Semiconductor Physics         Intrinsic Semiconductors- Conductivity, atomic and crystal structure of germanium and silicon, covalent bonds, generation and recombination, effect of temperature on conductivity of intrinsic semiconductors.         8         1           2         Semiconductor Physics         Extrinsic semiconductor RN type semiconductors and their conductivity. Definition of Drift and Diffusion currents.         8         2           3         Semiconductor Devices         For juncton dicke, mechanism of current flow in PN junction dicke, watarior dicke, Schotty diode, tunnel diode).         8         2           3         Rectifiers & Wave Shaping Circuit         Concept of rectification of rectifiers, basic concept of filtrating and filtering circuits. Working and use of voltage-doubler circuit. Basic concept of clipping and charging circuits.         8         3           4         Bipolar Junction         Charge carriers. PNP and NPN transistor set of shape current Standard notation for current and voltage polarity. (B, CE and CC configurations, (A) Common base configuration (CB): inputs and output characteristics, (Carcent of teakage current in terms of base current and leakage current applification factor. (B)Common emitter configuration, current and piffication. Transistor         8         4           5         Biplar Junction         Expression for emitter current in terms of base current and leakage current apprind current in terms of base current and leakage curr										
No.         Title of the Unit         Hrs.         CO           1         Semiconductor         Intrinsic Semiconductors-Conductivity, atomic and crystal structure of germainum and silicon, covalent bonds, generation and recombination, effect of temperature on conductivity of intrinsic semiconductors. Extrinsic semiconductors and their conductivity, Eritistic semiconductors. Extrinsic semiconductors and their conductivity, Eritistic semiconductors and their conductivity. Eritistic semiconductors for the N punction, Zener and valanche periadown, Semiconductor to special purpose diodes (Zener diode, LED, photo diode, varactor finded, Statistic static and dynamic resistances, Introduction to special purpose diodes (Zener diode, Statistic and dynamic resistances, Introduction to special purpose diodes (Cener diode, IED, photo diode, varactor finded, Schotty dode, tumed lidoe).         8         2           3         Rectifiers & Wave Shaping Circuit         Concept of rectification efficiency of rectifiers basic concept of filtrating and filtering and rectification efficiency of rectifiers hasic concept of clipping and theriging circuits. Working and use of voltage-doubler circuit. Basic concept of clipping and therging circuits.         8         3           4         Bipolar         Charge carriers, PNP and NPN transistors, their symbols and mechanisms of current flow in and voltage polarity. CB, CE and CC configurations. (A) Common subtro on farsitor parameters (input and output dynamic resistance, current application factor. (BCOmmon emitter configuration: current relations in CE configuration. CleCo), relations for torrent and helakage current in CB and CE configuration, input and output characteristics, determination of CB configuration. Thesistate equation and drawing it on collector bracterist		Detailed and	ary 515 01 <b>D5</b> 1		ineution us un umpriner	·	Contac	M	annad	
1       Semiconductor Physics       Intrinsic Semiconductors Conductivity, atomic and crystal structure of germanium and silicon, covalent bonds, generation and recombination, effect of temperature on conductivity of intrinsic semiconductors, energy levels diagram of conductor, insulators and intrinsic semiconductors, energy levels diagram of conductor, insulators and intrinsic semiconductors, energy levels diagram of conductor, insulators and intrinsic semiconductors, energy levels diagram of conductor, Definition of Drift and Diffusion currents.       8       1         2       Semiconductor Devices       PN junction diode, mechanism of current flow in PN junction. Zener and avalanche breakdown, Semiconductor diode characteristics, static and dynamic resistances. Introduction to special purpose diodes (Zener diode, LED, photo diode, varactor diode, Schottky diode, tunnel diode).       8       2         3       Rectifiers & Wave Shaping Circuit       Concept of rectification of rectifier operation calculations of ripple factor and rectification efficiency of rectifiers, basic concept of filtrating and litering circuits. Working and use of voltage-doubler circuit. Basic concept of lighting and charging circuits.       8       3         4       Bipolar Junction Transistor       Common base configuration (CB): inputs and output characteristics, determination, collector current in terms of base current (ICEO), relationship between the leakage current in CB and CE configurations in publication actor. B/Common chiler configuration for collector configuration. Expression for or mitter current in terms of base current (ICEO), relationship between the leakage current in CE configuration for low frequency voltage amplification. Typical application of CB configuration for low frequency vol		Title of	the Unit							
2       Semiconductor Devices       PN junction diode, mechanism of current flow in PN junction, Zener and avalanche breakdown, Semiconductor diode characteristics, static and dynamic resistances. Introduction to special purpose diodes (Zener diode, LED, photo diode, varactor diode, Schottky diode, tunnel diode).       8       2         3       Rectifiers & Wave Shaping Circuit       Concept of rectification, specification of rectifier diode, single-phase half wave, full wave, bridge rectifier circuits and their operation calculations of ripple factor and rectification efficiency of rectifiers, basic concept of filtrating and filtering thrau and their operation calculations of ripple factor and rectification efficiency of rectifiers, basic concept of clipping and charging circuits.       3         Charge carriers, PNP and NPN transistors, their symbols and mechanisms of current flow, explanation of fundamental current relations. Concept of leakage current. Standard notation for current and voltage quolarity. CB: CE and CC configurations. (A) Common base configuration (CB): inputs and output characteristics, determination of transistor (ICEO), relationship between the leakage current in CB and CE configuration, input and output characteristics, determination of dynamic input and output resistance and current amplification. TC configuration of CB and CE configuration of CB configuration collector configuration in the regards to dynamic input and output resistance and current amplification. Typical application of CB configuration of and and and package current in CE configuration of configuration for low frequence yvoltage amplifier in CE configuration of configuration of package current isinal voltage and current amplification factor faxing the operating points, effect of <td>1</td> <td></td> <td></td> <td>and silico conducti insulator Extrinsic</td> <th>on, covalent bonds, govity of intrinsic sen s and intrinsic semicos s semiconductor P&amp;</th> <td>eneration and recombination, effect of temperature on niconductors, energy levels diagram of conductor, onductors. XN type semiconductors and their conductivity,</td> <td>8</td> <td></td> <td>1</td>	1			and silico conducti insulator Extrinsic	on, covalent bonds, govity of intrinsic sen s and intrinsic semicos s semiconductor P&	eneration and recombination, effect of temperature on niconductors, energy levels diagram of conductor, onductors. XN type semiconductors and their conductivity,	8		1	
3       Rectifiers & Wave Shaping Circuit       full wave, bridge rectifier circuits and their operation calculations of ripple factor and rectification efficiency of rectifiers, basic concept of filtrating and filtering circuits. Working and use of voltage-doubler circuit. Basic concept of clipping and charging circuits.       8       3         4       Image: Concept of leakage current (ICBO) effect of temperature on leakage current. Standard notation for current and voltage polarity. CB, CE and CC configurations. (A) Common base configuration (CB): inputs and output characteristics, determination of transistor parameters (input and output) dynamic resistance, current amplification factor. (B)Common emitter configuration: current relations in CE configuration, collector current in terms of base current and leakage current (ICEO), relationship between the leakage current in CB and CE configuration, input and output characteristics, determination of dynamic input and output resistance and current amplification factor B from the characteristics. (C) Common collector configuration: Expression for emitter current in terms of base current and leakage current in CC configuration. (Comparison of CB and CE configuration of CB configuration in amplification. Transistor as an amplifier in CE configuration in amplification. Transistor as an amplifier in CE configuration of Small signal voltage and current gain of a basic transistor as an amplifier using CE output characteristic and DC load line, Concept of power gain as a product of voltage gain and current gain.       8       5         5       BJT Biasing       Different transistor biasing circuits for fixing the operating points, effect of temperature on operating point in cut-off or saturation region on performance of amplifier. Calculation of operating point for different biasing circuit. References Books:<	2			PN junct breakdov Introduct	ion diode, mechanisn wn, Semiconductor d tion to special purpo	n of current flow in PN junction, Zener and avalanche liode characteristics, static and dynamic resistances. se diodes (Zener diode, LED, photo diode, varactor	8		2	
4       Bipolar       current flow, explanation of fundamental current relations.       Concept of leakage current (ICBO) effect of temperature on leakage current. Standard notation for current and voltage polarity. CB, CE and CC configurations. (A) Common base configuration (CB): inputs and output characteristics, determination of transistor parameters (input and output) dynamic resistance, current amplification, collector current in terms of base current and leakage current (ICEO), relationship between the leakage current in CB and CE configuration, input and output characteristics, determination of dynamic input and output resistance and current amplification factor B from the characteristics. (C) Common 8       4         4       Bipolar       Transistor       8       4         5       Bipolar       0.200 configuration. Transistor B from the characteristics. (C) Common 8       4         6       Bipolar       0.200 configuration. Configuration.       8       4         7       Transistor       Configuration of the adage current in terms of base current and leakage current amplification. Torsis or as an amplifier in CE configuration of B configuration in amplification. Transistor amplifier in CE configuration for low frequency voltage and current gain of a basic transistor amplifier using CE output characteristic and DC load line, Concept of power gain as a product of voltage gain and and current gain.       8       5         5       BJT       Different transistor biasing circuits for fixing the operating points, effect of temperature on operating point. Need and method for stabilization of operating point for different biasing circuit. Simple design problems on poten	3	Wave	Shaping	full wave and recticircuits.	full wave, bridge rectifier circuits and their operation calculations of ripple factor and rectification efficiency of rectifiers, basic concept of filtrating and filtering circuits. Working and use of voltage-doubler circuit. Basic concept of clipping and					
5       BJT Biasing       temperature on operating point. Need and method for stabilization of operating point. Effect of fixing operating point in cut-off or saturation region on performance of amplifier. Calculation of operating point for different biasing circuits, use of Thevenin's theorem in analysing potential divider biasing circuit. Simple design problems on potential divider biasing circuit.       8       5         References Books:         Fundamental of Electrical Engs. – Ashfaq Husain	4	Jun	ction	current fl Concept Standard (A) Con determin current a CE confi (ICEO), input an resistanc collector leakage o Compari resistanc low freq amplifica equation signal vo character and current	Charge carriers, PNP and NPN transistors, their symbols and mechanisms of current flow, explanation of fundamental current relations. Concept of leakage current (ICBO) effect of temperature on leakage current. Standard notation for current and voltage polarity. CB, CE and CC configurations. (A) Common base configuration (CB): inputs and output characteristics, letermination of transistor parameters (input and output) dynamic resistance, current amplification factor. (B)Common emitter configuration: current relations in CE configuration, collector current in terms of base current and leakage current ICEO), relationship between the leakage current in CB and CE configuration, nput and output characteristics, determination of dynamic input and output resistance and current amplification factor B from the characteristics. (C) Common collector configuration. Comparison of CB and CE configuration. Comparison of CB and CE configuration. Comparison of CB and CE configuration. Transistor as an amplifier in CE configuration for ow frequency voltage amplification. Typical application of CB configuration in amplification. Transistor as an amplifier in CE configuration. (a) DC load line, its equation and drawing it on collector characteristics. (b) Determination of small signal voltage and current gain of a basic transistor amplifier using CE output					
Fundamental of Electrical Engg. – Ashfaq Husain		BJT Biasing BJT Biasing bint. Effect of fixing operating point in cut-off or saturation region on performance of amplifier. Calculation of operating point for different biasing circuits, use of Thevenin's theorem in analysing potential divider biasing circuit.							5	
	Referen	ces Books:								
			rical Engg. – A	shfaa Husai	n					
				•						



#### e-Learning Source:

https://nptel.ac.in/

PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PSO1	PSO2	PSO3	PSO4
CO1		3	2		1	1	1			2	
CO2		2	2		1					2	
CO3		2	2	3	2	3	2			3	
CO4		2	2							2	
CO5		2	3				2			2	

#### 1-Low Correlation; 2- Moderate Correlation; 3- Substantial Correlation

Name & Sign of Program Coordinator



Effective from Session: 2024-25											
Course Code	-	Title of the Course	BASIC ELECTRICAL ENGINEERING-I	L	Т	Р	С				
Year	First	Semester	First	3	1		-				
Pre-Requisite		Co-requisite									
	1. Fundamen	tal of current, volt	age and power and would be able to utilize in	elect	rical						
Course	engineering.										
Objectives	2. Study and	verification of ele	ctrical laws and network theorems for AC &	DC ci	rcuit	s.					

Course	e Outcomes
CO1	Conceptualize the fundamental of current, voltage and power and would be able to utilize in electrical heating
	and mechanical work.
CO2	Study the basic laws and DC network theorem which will apply to analyze the different electrical machines and
	network problems.
CO3	Develop the concept of magnetic flux and analogy between electric and magnetic circuit used in all engineering
	field.
CO4	Importance of ac circuit ,power factor and resonance in RLC circuit.
CO5	To impart knowledge of poly phase system and its application eg Electrical machine.

Title of the Unit		Contact	Mapped
		Hrs.	CO
Introduction of Electrical Engineering	Application of Electrical Engineering in different fields. Basic terminology: Current, Voltage and EMF, Resistor, Capacitor. Series and parallel combination of Resistors and Capacitors. Concept of constant voltage sources and Constant current source, symbols and graphical representation, characteristics of ideal and practical sources. Conversion of voltage sources into current sources and vice versa.	8	1
D.C. Circuit, Lighting Schemes	of wiring. LAMPS: Fluorescent and Incandescent lamp construction and working.	8	2
Electromagnetism	(formula based numerical problem). Concept of reluctance and MMF (formula based numerical problem). Analogy between electric and magnetic circuit, B – H curve, Faraday's Law of electromagnetic induction. Lenz's Law, Energy stored in inductor.	8	3
A.C. circuit	alternating current and voltage ,different types of power (Simple numerical problem), Difference between A.C. and D.C. Concept of phase and phase difference, Phasor representation of voltage and current for inductor, capacitor and	8	4
	Introduction of Electrical Engineering D.C. Circuit, Lighting Schemes Electromagnetism	Application of Electrical Engineering in different fields. Basic terminology: Current, Voltage and EMF, Resistor, Capacitor. Series and parallel combination of Resistors and Capacitors. Concept of constant voltage sources and Constant current source, symbols and graphical representation, characteristics of ideal and practical sources. Conversion of voltage sources into current sources and vice versa.D.C. Circuit, Lighting SchemesKVL & KCL, Ohm's law and simple numerical problems based on it. Introduction to Thevenin, Norton and Superposition theorem. LIGHTING SCHEMES: Lux, Candela, Series and parallel connection of wiring. LAMPS: Fluorescent and Incandescent lamp construction and working.ElectromagnetismConcept of magnetic flux, flux density, magnetic field intensity (formula based numerical problem). Concept of reluctance and MMF (formula based numerical problem). Analogy between electric and magnetic circuit, B – H curve, Faraday's Law of electromagnetic induction. Lenz's Law, Energy stored in inductor. Terminology: Instantaneous value, maximum value, cycle, frequency, alternating current and voltage and current for inductor, capacitor and representation of voltage and current for inductor, capacitor and resistor. Power factor ,RLC series resonance Introduction to three phase system, Advantage of three phase over single phase and line value of current	Introduction ofHrs.Introduction ofApplication of Electrical Engineering in different fields. Basic terminology: Current, Voltage and EMF, Resistor, Capacitor. Series and parallel combination of Resistors and Capacitors. Concept of 8 constant voltage sources and Constant current source, symbols and graphical representation, characteristics of ideal and practical sources. Conversion of voltage sources into current sources and vice versa.D.C. Circuit, Lighting SchemesKVL & KCL, Ohm's law and simple numerical problems based on it. Introduction to Thevenin, Norton and Superposition theorem. 8 LIGHTING SCHEMES: Lux, Candela, Series and parallel connection of wiring. LAMPS: Fluorescent and Incandescent lamp construction and working.ElectromagnetismConcept of magnetic flux, flux density, magnetic field intensity (formula based numerical problem). Concept of reluctance and MMF (formula based numerical problem). Analogy between electric and magnetic circuit, B – H curve, Faraday's Law of electromagnetic induction. Lenz's Law, Energy stored in inductor.A.C. circuitTerminology: Instantaneous value, maximum value, cycle, frequency, alternating current and voltage and phase difference, Phasor representation of voltage and current for inductor, capacitor and resistor. Power factor, RLC series resonance Introduction to three phase system, Advantage of three phase over single phase system. Star and Delta connection, Relationship between phase and line value of current

Unit-V		Types of A.C. and D.C. motors, Basic principle and working of A.C. and D.C. motor. Basic principle and working of A.C. and D.C. generator. Application of A.C. and D.C. motor. Single phase transformer (Brief introduction). Brief idea about stepper motor, reluctance motor and PMDC motor.	8	5						
Refere	References Books:									
1.	Fundamental of Ele	ectrical Engg. – Ashfaq Husain								
2.	Electrical Technolo	ogy Volume-I – B.L. Thereja								
e-Lear	ning Source:									
https://r	https://nptel.ac.in/									
	•									

PO-	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PSO1	PSO2	PSO3	PSO
PSO														4
CO														
CO1		3	2		1	1	1						2	
CO2		2	2		1				2				2	
CO3		2	2	3	2		2	2	1	2			3	
CO4		2	2			3		2					2	
CO5		2	3				2	3					2	

### 1-Low Correlation; 2- Moderate Correlation; 3- Substantial Correlation

Name & Sign of Program Coordinator



Effective from Session:											
Course Code	DED-101	Title of the Course	Engineering Drawing	L	Т	Р	С				
Year	Ι	Semester	Ι	3	1	0					
Pre-Requisite	10th	Co-requisite	-								
Course Objectives	To instill students about the importance of engineering drawing so students can understand the installation plan and can take different projects in their professional life.										

	Course Outcomes
CO1	Students' ability in legible writing letters and numbers will be improved.
CO2	Students' ability to perform basic sketching techniques and mechanical component drawing will be improved.
CO3	Students will be able to draw orthographic projections of different objects irrespective of number of dimensions and to develop
COS	pictorial views.
CO4	Students' ability to produce engineered drawing of any newly designed object will be improved.

Unit No.	Title of the Unit		Conta ct Hrs.	Mapped CO
1	Drawing, instruments and their uses and Introduction to Scales	Introduction to various drawing, instruments. Correct use and care of Instruments. Sizes of drawing sheets and their layouts. Lettering Techniques 1 Sheet Printing of vertical and inclined, normal single stroke capital letters. Printing of vertical and inclined normal single stroke numbers. Stencils and their use. Introduction to Scales: 1 Sheet Necessity and use, R F Types of scales used in general engineering drawing. Plane, diagonal and chord scales.	7	2
2	Conventional Presentaion, Principles of Projection and Dimensioning Techniques	Thread (Internal and External), Welded joint, Types of lines, Conventional representation of materials, Conventional representation of machine parts. <b>Principles of Projection:</b> Orthographic, Pictorial and perspective. Concept of horizontal and vertical planes. Difference between I and III angle projections. <b>Dimensioning Techniques:</b> Projections of points, lines and planes. 2 Sheet Orthographic Projections of Simple Geometrical Solids Edge and axis making given angles with the reference planes. Face making given angles with reference planes. Face and its edge making given angles with reference planes. Orthographic views of simple composite solids from their isometric views. Exercises on missing surfaces and views.	7	3
3	Section of Solids and Isometric Projection	Concept of sectioning Cases involving cutting plane parallel to one of the reference planes and perpendicular to the others. Cases involving cutting plane perpendicular to one of the reference planes and inclined to the others plane, true shape of the section Isometric Projection: 1 Sheet Isometric scale Isometric projection of solids.		2



		Use of squared paper	8	4
		Orthographic views of simple solids Isometric views of simple job like		
	Free hand sketching	carpentry joints		
4	and Development of Surfaces	Development of Surfaces: 1 Sheet		
	Surfaces	Parallel line and radial line methods of developments. Development of simple and truncated surfaces (Cube, prism, cylinder, cone and pyramid).		
		Assembly and Disassembly Drawings: 2 Sheet	10	3
		Plummer block		
		Footstep bearings		
		Couplings etc.		
	Assembly and Disassembly	Rivetted & Welded Joints		
	Drawings, Orthographic Projection of Machine Parts and Practice on AUTO CAD	Screw and form of screw thread		
5		Orthographic Projection of Machine Parts:		
		1 Sheet		
		Nut and Bolt, Locking device, Wall bracket		
		Practice on AUTO CAD:		
		To draw geometrical figures using line, circle, arc, polygon, ellipse, rectangle - erase and		
		other editing commands and osnap commands (two dimensional drawing only)		
		(Printouts of figures)		
Referen	nces Books:			
1. Engine	eering Drawing : ND Bhatt			
2. Engine	eering Drawing : R.K. Dha	wan		
3. Engine	eering Drawing : B.K.Goel			
e-Learni	ng Source:			
	=	bKSEnEFM&list=PLDN15nk5uLiD3MEUiqsYPnZOHcVu7um6_		
	· CI -			

PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PSO1	PSO2	PSO3	PSO4
CO1	3	2	2		2		1	-	2	1	-
CO2	3	3	2			2	2	2	3	-	2
CO3	2	3			2		1	3	-	2	1
CO4	2	3	2		2		2	-	2	-	-

# 1-Low Correlation; 2- Moderate Correlation; 3- Substantial Correlation

Name & Sign of Program Coordinator	Sign & Seal of HoD
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Effective fro	m Sessi	on:																
Course Cod	e	DPH	[-151	/251		Title o	of the (	Cours	^	•	Physics	Lab			L	Т	Р	С
Year		1 <sup>st</sup>				Semes			1 <sup>st</sup> / 2						0	0	3	
Pre-Requisi	te	Non	e			Co-ree	quisite	<b>)</b>	Non	e								
Course Obj	ectives																	
C01	hr	Course Outcomes o gain practical knowledge by applying the experimental methods to correlate with the Physics theory.																
C01 C02	Ex	xperience and understand basic physical fundamentals and the key vocabulary to describe them: basic Electronics & Electrical, nematics, dynamics, work and energy, gravitation, fluids.																
CO3		Develop skills in observation, interpretation, reasoning, synthesis, generalizing, predicting, and questioning as a way to learn new nowledge.																
CO4	Aŗ	Apply conceptual understanding of the physics to general real-world situations.																
Experimen No.		Title of the ExperimentContent of the Unit												Con Hr		Map CO		
1				De	termina	ation o	fʻg'u	sing si	mple pe	ndulum.					2		1	
2												f capillary r	se.		2		1	
3				То	determ	nine the	e frequ	ency of	of A.C. 1	nains by	using a	sonometer	and a horse s	hoe magnet.	2		1	
4				То	To determine the frequency of A.C. mains by using a sonometer and a horse shoe magnet. To determine the value of modulus of rigidity of given material of a wire by statical method										2		1	
5					ng Bar termin:				of visco	sity of v	vater by	capillary flo	w (Poiseuille	e's method)	2		2	
6									tower by			cupiliary inc	W (I OIBeulik	s method).	2		3	
7									Inertia d						2		3	
8											ance tube				2	r.	3	
9												office Box.			2	r.	3	
10				By	using	Potenti	omete	r, dete	rminatio	on of (i)	E1/E2 (i	i) Internal r	esistance of g	given cell.	2		4	
11				De	termina	ation of	f coeff	icient	of friction	on on a l	horizonta	al plane.			2		1	
12				De	termina	ation o	f visco	sity co	oefficien	t of a lu	bricant b	y Stoke's la	W.		2		4	
13				De	termina	ation o	f Sprin	ıg Con	istant.						2		4	
14				Ve	rificati	on of K	Kirchot	ff's lav	ws.						2		2	
15								stics o	f a p-n j	unction	diode.				2		3	
Note: Any to	en expe	erime	nts a	re to l	be per	forme	ed.											
References																		
	tan Phy				tal													
	lied Phy			-		1												
3. Prad	eep Fur	idame	ntal: C	ogia 8	e Gom	ber.												
C Learning 5	ource.																	
PO-PSO PO	PO2	PO2 PO3 PO4 PO5 PO6 PO7 PO8 PO9 PO10 PO11 PO12 PSO1 PSO2 PSO3										PSO3	PSO4	1	PSO5			
CO											2							
CO1 3												1		2	3		2	
CO2 3 CO3 2																	2	
CO3 2 CO4 3																	2	
004		1	1	1	1	1	1	1	1	1	1						4	



Effective from Sessi	Effective from Session:												
Course Code	DCAD-151	Title of the Course	Basic Computer Aided Design Lab	L	Т	Р	С						
Year	FIRST	Semester	FIRST			2							
Pre-Requisite	10 TH PASSED	Co-requisite											
Course Objectives	After the successful co	fter the successful completion, learner will develop following attributes.											

	Course Outcomes
CO1	Students will develop good communication skills and team work
CO2	Students will become familiar with office practice and standards.
CO3	Students will become familiar with Auto Cad's two-dimensional drawings.
CO4	Student's ability to convert sketches into engineered drawings will increase.
CO5	Students will be able to draw orthographic projections and sections.

Unit No.	Title of the Unit		Contact Hrs.	Mapped CO
1	AutoCAD	To study of Auto CAD software	2	CO1
2	Sketch and drafting	Study And Sketch of drafting setting.	2	CO2
3	Dimensional sketch	Study and sketch of Dimensional setting	2	CO3
4	Draw geometrical figure	Draw geometrical figure using drawing commands	2	CO4
5	Modify figure Scaling	To modify a geometrical figure using editing comment.	2	CO5
6	Orthographic	To draw orthographic view of a geometrical figure.	2	CO1
7	Isometric view	To Draw isometric view of a geometrical figure.	2	CO2
8	Different view	To Draw top front and side view of an isometric figure.	2	CO3
9	Sectional view	To draw sectional view of a solid object.	2	CO4
10	Scaling	To do practical on page set up & scaling of drawing.	2	CO5
Referen	nces Books:			
Autocad 1	book by Rohit Mongia			
o I comi	ing Sources			
	ing Source:			
-	ww.googleadservices.com			

PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PSO1	PSO2	PSO3	PSO4
CO1	3	2	3	2	2	1	1	3	3	3	1
CO2	2	2	3	2	1	1	2	3	1	1	3
CO3	1	3	1	2	2	1	2	1	3	3	2
CO4	2	3	2	2	1	2	3	2	1	2	3
CO5	2	2	3	2	3	1	3	2	2	1	2

#### 1-Low Correlation; 2- Moderate Correlation; 3- Substantial Correlation

Effective from Se	iffective from Session: 2024-25												
Course Code		Title of the Course	BASIC ELECTRICAL ENGINEERING-I LAB	L	т	Ρ	с						
Year	First	Semester	First			2	-						
Pre-Requisite		Co-requisite											
	1. Different e	electrical measurin	g instruments (Analog and Digital)										
Course	2. Study and	2. Study and verification of electrical laws and network theorems.											
Objectives													

Course	Outcomes
CO1	Familiarization of different electrical measuring instruments (Analog and Digital)
CO2	Verifying laws of series and parallel connection of circuit elements.
CO3	Verifying different DC network theorems and electrical machines.

Experiment No.	Experiment	Contact Hrs.	Mapped CO
Experiment-1	Use of ammeter, voltmeter and multimeter	2	1
Experiment-2	To verify the laws of series and parallel connections of resistance.	2	2
Experiment-3	To verify the laws of series and parallel connections of capacitance.	2	2
Experiment-4	Verification of Ohm's law.	2	2
Experiment-5	To verify Kirchhoff's first laws: The algebric sum of the currents at a junction is zero.	2	2
Experiment-6	To verify Kirchhoff's second laws: The algebric sum e.m.f. in any closed circuit is equal to the algebric sum of IR products (drops) in that circuit.	2	2
Experiment-7	To measure the resistance an ammeter and a voltmeter and to conclude that ammeter has very low resistance whereas voltmeter has very high resistance.	2	2
Experiment-8	To verify Thevenin's theorems.	2	3
Experiment-9	Study of 1-phase Energy meter.	2	3
Experiment-10	Study of running and reversing of a 3-phase Induction motor.	2	3
Experiment-11	Measurement of Efficiency of a 1- phase transformer by load test.	2	3
Experiment-12	Study of phenomenon of resonance in RLC series circuit.	2	3
Experiment-13	Practice in making different types of wiring and control of lamp with one or many switches.	2	2

PO-PSO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PSO1	PSO2	PSO3	PSO4
СО														
CO1			2					3	1	3			2	
CO2		1	3		2				1				2	
CO3		1	3		2				1				3	



#### Integral University,

Effective from Session: 2010-11										
Course Code	DWS-151	Title of the Course	WORKSHOP PRACTICE	L	Т	Р	С			
Year	Ι	Semester	I	0	0	3	30			
Pre-Requisite	Metric Qualified	Co-requisite								
Course Objectives	The Workshop Practice course is designed to provide hands-on experience with essential tools, machines, and techniques used in various engineering workshops. Students will learn the principles and operations of turning, tapering, threading, and grinding in the lathe shop, emphasizing precision machining and tool grinding. In the fitting and bench working shop, students will practice filing, drilling, tapping, dieing, and creating accurate male-female joints. The blacksmith shop focuses on foundational operations like upsetting, punching, bending, and swaging. Welding exercises include butt joints, lap joints, and oxy-acetylene welding. In the sheet metal shop, students will fabricate objects like funnels, trays, and electrical panel boxes with soldering and forming techniques. Carpentry introduces students to woodworking tools, joints like half-lap and mortise-tenon, and basic lathe operations. Finally, in the foundry, students will make moulds with single and multi-piece patterns, create cores, and cast aluminium. The course aims to equip students with practical skills and knowledge for effective problem-solving and application in mechanical engineering.									

	Course Outcomes				
CO1	To acquire skills in basic engineering practice.				
CO2	To identify the hand tools and instruments.				
CO3	To acquire measuring skills.				
CO4	To acquire practical skills in the trades.				
CO5	To provides the knowledge of job materials in various shops.				
CO5	To provides the knowledge of core technical subjects for making and working of any type of project.				

Jnit No.	Title of the Unit		Contact Hrs.	Mapped CO
		a. Study of tools and operations		CO1
		b. Plane turning		
1.	M 1: 01	c. Step turning	6	
1.	Machine Shop	d. Taper turning	0	
		e. Threading		
		f. Single point cutting tool grinding		
		a. Study of tools and operations		CO2
2.	Fitting Bench	b. Simple exercises involving filing work	3	
۷.	Working Shop	<ul><li>c. Making perfect male-female joint</li><li>d. Simple exercises involving drilling/tapping/die</li></ul>		
		a. Shiple exercises involving anning/tapping/die	3	CO2
	Black Smithy Shop	a. Study of tools and operations	5	02
3.		b. Simple exercises based on black smithy operations such as		
		c. Upsetting/drawing down, punching, bending, fullering and swaging		
4.		a. Study of tools and operations	6	CO3
	Welding Shop	b. Simple butt Joint		
		c. Lap Joint		
		d. Oxy acetylene welding		
5.		a. Study of tools and operations	3	CO4
	Sheet Metal Shop	b. Making funnel complete with soldering		
		c. Fabrication of tool box, tray, electrical panel box etc.		
6.	Carpentry Shop	a. Study of tools and operation and carpentry Joints.	3	CO5
		b. Simple exercise using jack plain		
		c. To prepare half lap corner, joint, mortise and tenon joints.		
		d. Simple exercise on woodworking lathe.		
7.		a. Making a mould using single piece pattern	6	CO5
	Foundry	b. Making a mould using two piece pattern		
		c. Making a mould using a pattern with core print		
		d. Making Pouring and Making an Aluminium Casting.		

**References Books:** 



#### Integral University,

Workshop Technology by R. S. Khurmi

#### e-Learning Source:

https://www.youtube.com/watch?v=sHbvMmOKdjg&list=PL8PvmC2cEsGSCry\_RY0Qk2PcsNI5DQZ-h&index=2

PO-PSO CO	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PO13
CO1	2	-	-	2	2	-	-	2	-	-	-	2	2
CO2		-	-	-	3	-	-	-	2	-	-	3	-
CO3	3	-	-	2		-	3	2	-	-	-	2	-
CO4	-	-	-	-	2	-	2	2	-	2	-	2	-
CO5	-	-	-	3	2	-	2	3	2	-	-	-	3
	3	-	-	-	-	2	2	2	-	-	3	-	2

Name & Sign of Program Coordinator	Sign & Seal of HoD